

# isc N-Channel MOSFET Transistor

# IXTH52N65X

#### FEATURES

- · With low gate drive requirements
- · Easy to drive
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

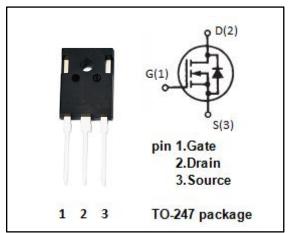
· Switching applications

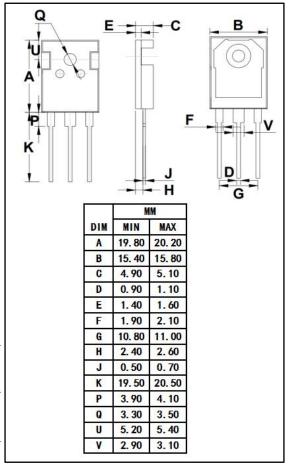
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
$V_{DSS}$	Drain-Source Voltage	650	V	
V <sub>GSS</sub>	Gate-Source Voltage	±30	V	
l <sub>D</sub>	Drain Current-Continuous	52	А	
Ірм	Drain Current-Single Pulsed	104	Α	
$P_{D}$	Total Dissipation	660	W	
Tj	Operating Junction Temperature	Junction Temperature -55~150		
T <sub>stg</sub>	Storage Temperature	-55~150	°C	

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	0.19	°C/W







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 250uA	650			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =±30V; I <sub>D</sub> = 250uA	3		5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 26A			68	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0V;@Tc=25°C Tc=125°C			10 100	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =52A, V <sub>GS</sub> = 0 V			1.4	V

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